## SPICE Device Model SQP100P06-9m3L



Vishay Siliconix

## P-Channel 60 V (D-S) 175 °C MOSFET

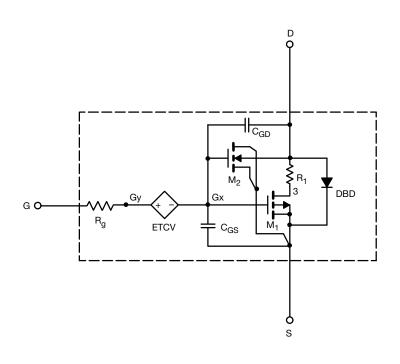
### DESCRIPTION

The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The sub-circuit model is extracted and optimized over the -55 °C to +125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage. A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C<sub>gd</sub> model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### SUBCIRCUIT MODEL SCHEMATIC

### **CHARACTERISTICS**

- P-Channel Vertical DMOS
- Macro Model (Sub-circuit model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the -55 °C to +125 °C Temperature Range
- Model the Gate Charge



#### Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



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<b>SPECIFICATIONS</b> ( $T_J = 25 \text{ °C}$ , unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	2	2	V
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -30 \text{ A}$	0.0072	0.0072	Ω
		$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -20 \text{ A}$	0.0103	0.0102	
Forward Transconductance a	g <sub>fs</sub>	V <sub>DS</sub> = -15 V, I <sub>D</sub> = -30 A	81	82	S
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> = -80 A	-0.96	-0.95	V
Dynamic <sup>b</sup>					
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = -25 V, V <sub>GS</sub> = 0 V, f = 1 MHz	9500	9605	pF
Output Capacitance	C <sub>oss</sub>		1030	1030	
Reverse Transfer Capacitance	C <sub>rss</sub>		748	750	
Total Gate Charge	Qg	V <sub>DS</sub> = -30 V, V <sub>GS</sub> = - 10 V, I <sub>D</sub> = -100 A	193	189	nC
Gate-Source Charge	Q <sub>gs</sub>		30	30	
Gate-Drain Charge	Q <sub>gd</sub>		54	54	

Notes

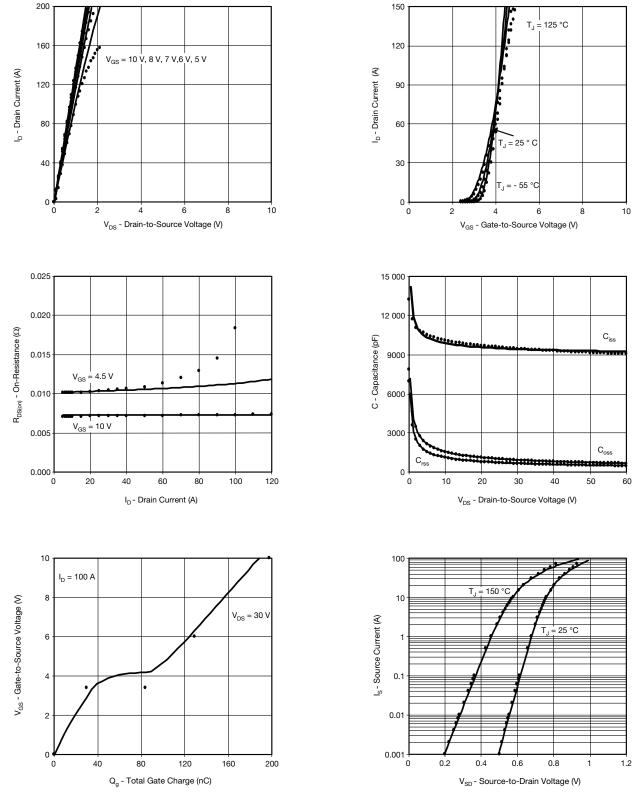
a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.



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### COMPARISON OF MODEL WITH MEASURED DATA (T<sub>J</sub> = 25 °C, unless otherwise noted)



#### Note

• Dots and squares represent measured data. Copyright: Vishay Intertechnology, Inc.

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